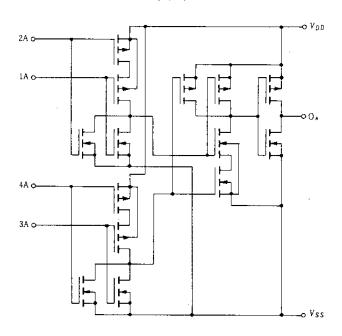
## HD14002B

#### Dual 4-input NOR Gate

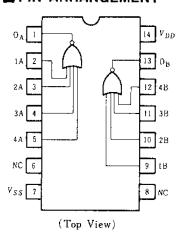
#### **FEATURES**

- Quiescent Current = 0.5nA typ/pkg @5V
- Noise Immunity = 45% of  $V_{DD}$  typ Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for Pin Replacements for CD4002B and MC14002B Series

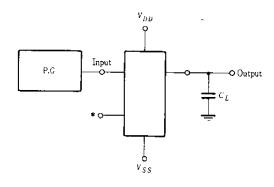
#### **■ CIRCUIT SCHEMATIC** (1/2)



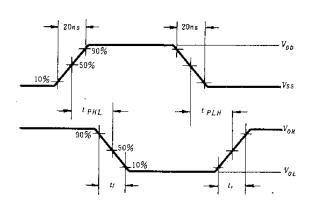
#### ■ PIN ARRANGEMENT



#### SWITCHING TIME TEST CIRCUIT



\* All Unused inputs of OR, NOR gates must be connected to  $V_{SS}$ 



#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol		Test Conditions	<b>−40</b> °C		<b>25</b> °C			85°C		77	
Onaracter 19th	Symoon	$V_{DD}(V)$	Test Conditions	min	max	min	typ	max	min	max	Unit	
Output Voltage		5.0	$V_{in} = V_{DD}$		0.05	_	0	0.05	_	0.05	v	
	Vol	10		_	0.05	_	0	0.05	-	0.05		
		15		_	0.05	ı	0	0.05	_	0.05		
	Voн	5.0	$V_{in}=0$	4.95	_	4.95	5.0		4.95	_	v	
		10		9.95		9.95	10	+	9.95			
		15		14.95		14.95	15		14.95	_		
Input Voltage		5.0	$V_{out} = 4.5 \mathrm{V}$	_	1.5	_	2.25	1.5	-	1.5		
	$V_{IL}$	10	$V_{out} = 9.0 \text{V}$	_	3.0		4.50	3.0	_	3.0	•	
		15	$V_{out}=13.5\mathrm{V}$	_	4.0		6.75	4.0	_	4.0		
	ļ	5.0	$V_{out} = 0.5 \text{V}$	3.5		3.5	2.75		3.5		v	
	$V_{IH}$	10	$V_{out} = 1.0 \text{V}$	7.0		7.0	5.50	_	7.0	_		
	<u> </u>	15	$V_{out} = 1.5 \text{V}$	11.0		11.0	8.25	_	11.0	_		
Output Drive Current	Іон	5.0	$V_{OH}=2.5\mathrm{V}$	-2.5	_	-2.1	-4.2	-	-1.7	-	mA.	
		5.0	$V_{OH} = 4.6 \text{V}$	-0.52	_ '	-0.44	-0.88	_	-0.36			
		10	$V_{OH} = 9.5 \text{V}$	-1.3	-	-1.1	-2.25	1	-0.9	_		
		15	$V_{OH}=13.5\mathrm{V}$	-3.6	_	-3.0	-8.8	_	-2.4			
	IoL	5.0	$V_{OL}=0.4V$	0.52	-	0.44	0.88	_	0.36	ana	1	
		10	$V_{OL}=0.5V$	1.3	_	1.1	2.25	_	0.9	_	mА	
		15	$V_{OL}=1.5V$	3.6	_	3.0	8.8	_	2.4			
Input Current	$I_{in}$	15		<u> </u>	±0.3	-	±0.00001	±0.3	_	±1.0	μΑ	
Input Capacitance	Cin	_	$V_{in}=0$	_	_	<u> </u>	5.0	7.5	· –	_	рF	
Quiescent Current	IDD	5.0	Zero Signal, per Package	<u> </u>	1.0	-	0.0005	1.0	_	7.5		
		10			2.0		0.0010	2.0		15.0	<b>⊣</b>	
		15	por rachago		4.0		0.0015	4.0	-	30.0		
Total Supply Current*	Ιτ	5.0	Dynamic+I <sub>DD</sub> , C <sub>L</sub> =50pF per Gate, f=1kHz		_	_	0.3		_	_	μ <b>A</b>	
		10					0.6		_	_		
		15		_	_	-	0.9	-				

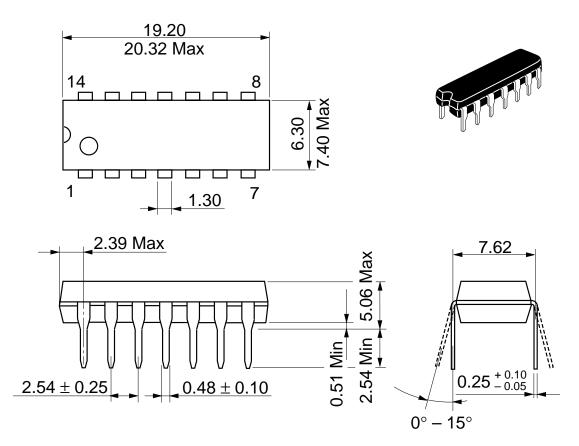
 $<sup>\</sup>ensuremath{\bigstar}$  To calculate total supply current at frequency other than IkHz.

### **SWITCHING CHARACTERISTICS** ( $C_L = 50 \text{pF}$ , $Ta = 25 ^{\circ}\text{C}$ )

Characteristic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit	
Output Rise Time		5.0		100	200		
	t r	10	-	50	100	ns	
		15		40	80		
Output Fall Time		5.0	-	100	200		
	$t_f$	10	_	50	100	ns	
	!	15		40	80		
Propagation Delay Time		5.0	_	160	320		
	t <sub>PLH</sub>	10	_	65	130	ns	
		15	_	50	100	<u> </u>	
	tрнL	5.0	_	160	320		
		10		65	130	ns	
		15	_	50	100	1	

 $<sup>@</sup>V_{DD} = 5.0 V \\ I_{T} = (0.3 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ @V_{DD} = 15 V \\ I_{T} = (0.9 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ @V_{DD} = 10 V \\ I_{T} = (0.6 \mu \text{A/kHz}) \\ f + I_{DD}/2 \\ \\ & V_{DD} = 10 V \\$ 

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

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